

In the Specification:

Please insert before the first paragraph of the application:

This application is the national stage application of international application number PCT/DE2003/003044, filed on September 13, 2003, which claims the benefit of priority to German Patent Application DE 102 42 877.8, filed on September 16, 2002, incorporated herein by reference.

Please rewrite the paragraph on page 1, lines 23-30 as follows:

Furthermore, integrated capacitors in logic and analogue semiconductor circuits represent a considerable additional outlay. This applies in particular to high-density so-called "embedded DRAMs" since the highly optimized and highly space-saving cell design of modern DRAMs requires a fabrication process which can no longer easily be combined with a logic process.

Please delete the paragraph on page 5, lines 20-21.